Vishay Siliconix

Low Voltage, Dual Supply, Low Ron, Quad SPST Analog Switches

DESCRIPTION

The DG9424, DG9425, DG9426 are low voltage precision monolithic quad single-pole-single-throw analog switches.

Using BiCMOS wafer fabrication technology allows the DG9424, DG9425, DG9426 to operate on single and dual supplies. Single supply voltage ranges from 3 V to 12 V while dual supply operation is recommended with \pm 3 V to \pm 6 V.

Combining high speed (t_{ON} : 42 ns), flat $R_{DS(on)}$ over the analog signal range (Ω), minimal insertion lose (-3 dB at 190 MHz), and excellent crosstalk and off-isolation performance, the DG9424, DG9425, DG9426 are ideally suited for audio and video signal switching.

The DG9424 and DG9425 respond to opposite control logic as shown in the truth table. The DG9426 has two normally open and two normally closed switches.

FEATURES

- 2.7 V thru 12 V single supply or ± 3 thru ± 6 dual supply
- On-resistance $R_{DS(on)}$: 1.7 Ω
- Fast switching ton: 42 ns
 - t_{OFF}: 28 ns
- TTL, CMOS compatible
- Low leakage: 0.2 nA
- 2000 V ESD protection

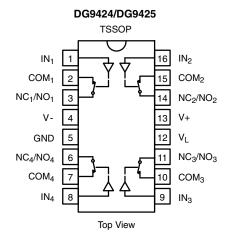
BENEFITS

- Widest dynamic range
- · Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing

APPLICATIONS

- · Automatic test equipment
- Data acquisition systems
- · Communication systems
- ADC systems
- xDSL and PBX / PABX
- · Audio signal routing

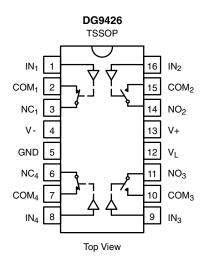
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE						
LOGIC	DG9424	DG9425				
0	OFF	ON				
1	ON	OFF				

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FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE						
LOGIC	SW ₁ , SW ₄	SW ₂ , SW ₃				
0	ON	OFF				
1	OFF	ON				

ORDERING INFORMATION						
TEMP. RANGE	PACKAGE	PART NUMBER				
		DG9424DQ-T1-E3				
-40 °C to +85 °C	16-Pin TSSOP	DG9425DQ-T1-E3				
		DG9426DQ-T1-E3				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	PARAMETER		UNIT					
V+ to V-		-0.3 to +13						
GND to V-		7	V					
V _L		(GND - 0.3) to (V+) + 0.3	V					
IN, COM, NC, NO ^a		(V-) - 0.3 to (V+) + 0.3						
Continuous Current (NO, NC, COM Pins)	Continuous Current (NO, NC, COM Pins)		Λ					
Peak Current, S or D (Pulsed 1 ms, 10 % Duty Cycle)		200	mA					
Storage Temperature		-65 to +150	°C					
Power Dissipation (Package) b	16 Din TCCOD 0	450	mW					
Thermal Resistance ^b	16-Pin TSSOP ^c	178	°C/W					

Notes

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 7 mW/°C above 25 °C.



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PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 12 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. c	MAX. d	J
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	0	-	12	V
On-Resistance	R _{ON}	V+ = 10.8 V, V- = 0 V	Room	-	1.8	3	Ω
On resistance	TION	I_{NO} , $I_{NC} = 50$ mA, $V_{COM} = 2 \text{ V} / 9 \text{ V}$	Full	-	-	4	32
Digital Control							
Input Current	I _{INL} or I _{INH}		Full	-1	0.01	1	μΑ
Dynamic Characteristics							
Turn-On Time ^e	tou		Room	ı	42	57	
Turn-Oil Time	t _{ON}	$R_L = 300 \Omega, C_L = 35 pF$	Full	ı	-	65	
Turn-Off Time ^e	V_{NO} , $V_{NC} = 5$ V, see fig. 2	Room	ı	28	42	ns	
Turn-Oil Tillie	t _{OFF}		Full	ı	-	44	
Break-Before-Make Time Delay ^e	t _D	DG9426 only, V_{NO} , V_{NC} = 5 V R_L = 300 Ω , C_L = 35 pF	Room	2	-	-	
Charge Injection ^e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	38	-	рС
Off-Isolation ^e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	-	-56	-	dB
Channel-to-Channel Crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-77	-	ив
NO, NC Off Capacitance e	C _{NO(off)}		Room	-	49	-	pF
NO, NO OII Capacitance	C _{NC(off)}	f = 1 MHz	Room				
COM Off Capacitance e	C _{COM(off)}	I = I IVINZ	Room	ı	37	-	рг
Channel On Capacitance e	C _{COM(on)}		Room	1	89	-	
Power Supplies							
Positive Supply Current	l+		Room	-	0.02	1	
Positive Supply Current	I+		Full	1	-	5	
Negative Supply Current		V 0V	Room	-1	-0.002	-	
	l-		Full	-5	-	-	
Logic Supply Current	IL	$V_{IN} = 0$ or V_L	Room	-	0.002	1	μΑ
Logic Supply Current			Full	-	-	5	
Ground Current	L		Room	-1	-0.002	-	
Ground Current	I _{GND}		Full	-5	-	-	



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PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, V- = 5 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. °	MAX. d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	-5		5	V
On-Resistance	R _{ON}	V+ = 4.5 V, V- = -4.5 V	Room	-	2	3.3	Ω
I _{NO} , I _{NC} = 50 III	I_{NO} , $I_{NC} = 50$ mA, V_{NO} , $V_{COM} = \pm 3.5$ V	Full	-	-	4.3		
	I _{NO(off)}		Room	-1	-	1	
Switch Off Leakage Current	I _{NC(off)}	V+ = 5.5 V, V- = -5.5 V	Full	-10	-	10	
Ownor on Lounage Garrent	I _{COM(off)}	$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	nA
	'COM(OII)		Full	-10	-	10	.,,
Channel On Leakage Current	I _{COM(on)}	V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	
Charmer On Leakage Current	'COM(on)	V_{NO} , $V_{NC} = V_{COM} = \pm 4.5 \text{ V}$	Full	-10	-	10	
Digital Control							
Input Current ^a	I _{INL} or I _{INH}		Full	-1	0.05	1	μΑ
Dynamic Characteristics							
Turn-On Time ^e	+		Room	-	48	67	ns
rum-On Time °	t _{ON}	$R_L = 300 \ \Omega, C_L = 35 \ pF$ $V_{NO}, V_{NC} = \pm 3.5 \ V, see fig. 2$	Full	-	-	81	
Turn-Off Time ^e	+		Room	=	34	57	
Turn-On Time 5	t _{OFF}		Full	-	-	67	
Break-Before-Make Time Delay ^e	t _D	DG9426 only, V_{NO} , V_{NC} = 3.5 V R_L = 300 Ω , C_L = 35 pF	Room	2	-	ı	
Charge Injection e	Q _{INJ}	$V_{g} = 0 \text{ V}, R_{g} = 0 \Omega, C_{L} = 1 \text{ nF}$	Room	-	112	-	рС
Off Isolation ^e	OIRR	D 500 C 5 7 f 1 MIL-	Room	-	-56	-	40
Channel-to-Channel Crosstalk e	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room	-	-82	-	dB
Source Off Capacitance e	$C_{NO(off)} \ C_{NC(off)}$		Room	-	38	-	
Drain Off Capacitance e	C _{COM(off)}	f = 1 MHz	Room	-	38	-	pF
Channel On Capacitance e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Positive Supply Current ^e	I+		Room	-	0.03	1	
1 John Vo Guppiy Guirent	IT		Full	-	-	5	
Negative Supply Current ^e	l-		Room	-1	-0.002	-	
gaaro oappij odnont		$V_{IN} = 0$ or V_L	Full	-5	-	-	μΑ
Logic Supply Current ^e	ΙL	VIN — O OI VL	Room	-	0.002	1	μΑ
Logic Supply Current	IL		Full	-	-	5	
Ground Current e	e I	Room	-1	-0.002	-		
Ground Current e	I _{GND}		Full	-5	-	-	



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SPECIFICATIONS a Single	e Supply 5	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, $V- = 0 VV_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	-	-	5	V
On-Resistance e	R _{ON}	$V+ = 4.5 \text{ V}, I_{NO}, I_{NC} = 50 \text{ mA},$	Room	-	3.4	4.8	Ω
On-nesistance	PON	VCOM = 1 V, 3.5 V	Full	-	-	5.8	22
Dynamic Characteristics							
Turn-On Time ^e	+		Room	-	71	86	
rum-on time °	t _{ON}	$R_{L} = 300 \Omega, C_{L} = 35 pF$	Hot	-	-	106	ns
T 0"T' 0	t _{OFF}	V_{NO} , $V_{NC} = 3.5 \text{ V}$, see fig. 2	Room	-	37	51	
Turn-Off Time ^e			Hot	-	-	56	
Break-Before-Make Time Delay ^e	t _D	DG9426 only, V_{NO} , V_{NC} = 3.5 V R_L = 300 Ω , C_L = 35 pF	Room	5	-	-	
Charge Injection ^e	Q _{INJ}	$V_g = 0 \text{ V}, \text{ R}_g = 0 \Omega, \text{ C}_L = 1 \text{ nF}$	Room	-	10	-	рС
Power Supplies							
Docitive Cumply Current 6	I+		Room	-	0.02	1	
Positive Supply Current ^e			Hot	-	-	5	
Negative Cumply Cumpet 6			Room	-1	-0.002	-	
Negative Supply Current ^e	I-	V _{IN} = 0 or V _L	Hot	-5	-	-	
Logio Supply Current 6	I.		Room	-	0.002	1	μA
Logic Supply Current ^e	Ι <u>ι</u>		Hot	1	-	5	
Ground Current ^e			Room	-1	-0.002	-	
Ground Current °	I_{GND}		Hot	-5	-	-	



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SPECIFICATIONS a Sing	le Supply 3	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 3 V, V- = 0 V $V_L = 3 V, V_{IN} = 2.4 V, 0.4 V^f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range e	V _{ANALOG}		Full	0	-	3	V
On-Resistance	R _{ON}	V+ = 2.7 V, V- = 0 V	Room	ı	8	13.8	Ω
On-nesistance	HON	I_{NO} , $I_{NC} = 5$ mA, $V_{COM} = 0.5$ V, 2.2 V	Full	ı	-	15.1	22
	I _{NO(off)}		Room	-1	-	1	
Switch Off Leakage Current ^a	I _{NC(off)}	V+ = 3.3 V, V- = 0 V	Full	-10	-	10	
Switch On Leakage Current		$V_{COM} = 0.3 \text{ V}, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room	-1	-	1	nΛ
	ICOM(off)		Full	-10	-	10	nA
Channal On Lookaga Current 8		V+ = 3.3 V, V- = 0 V,	Room	-1	-	1	
Channel On Leakage Current ^a	I _{COM(on)}	$V_{NO}, V_{NC} = V_{COM} = 0.3 \text{ V}, 3 \text{ V}$	Full	-10	-	10	
Digital Control e							
Input Current	I _{INL} or I _{INH}		Full	-1	0.005	1	μΑ
Dynamic Characteristics							
Turn-On Time	+		Room	1	140	163	
rum-on time	t _{ON}	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Full	ı	-	193	
Furn-Off Time	+	V_{NO} , $V_{NC} = 1.5 \text{ V}$, see fig. 2	Room	ı	65	80	ns
Turn-On Time	t _{OFF}		Full	-	-	89	.,.
Break-Before-Make Time Delay	t _D	DG9426 only, V_{NO} , V_{NC} = 1.5 V R_L = 300 Ω , C_L = 35 pF	Room	5			
Charge Injection e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	15	-	рС
Off Isolation e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	-	-56	-	dB
Channel-to-Channel Crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-80	-	иь
Course Off Consoitance 6	C _{NO(off)}		Doom	_	F0		
Source Off Capacitance e	C _{NC(off)}	f _ 1 MU~	Room	-	53	_	nE
Drain Off Capacitance e	C _{COM(off)}	f = 1 MHz	Room	i	42	1	pF
Channel On Capacitance e	C _{COM(on)}		Room	-	92	-	

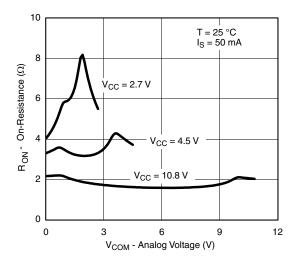
Notes

- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test.
- b. Room = 25 °C, Full = As determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = Input voltage to perform proper function.

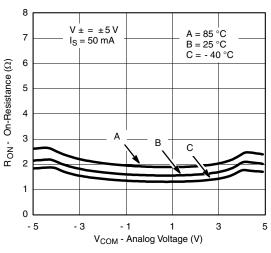
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



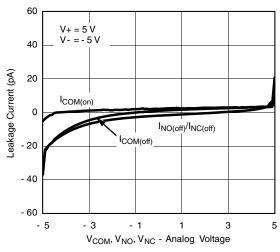
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



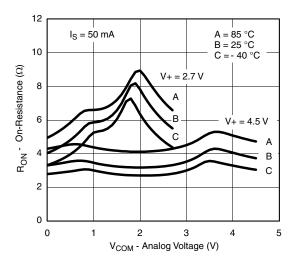
RON vs. VCOM and Supply Voltage



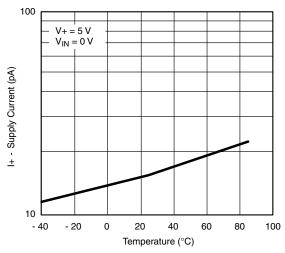
R_{ON} vs. Analog Voltage and Temperature



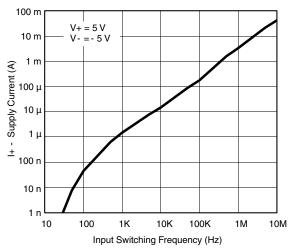
Leakage Current vs. Analog Voltage



R_{ON} vs. Analog Voltage and Temperature



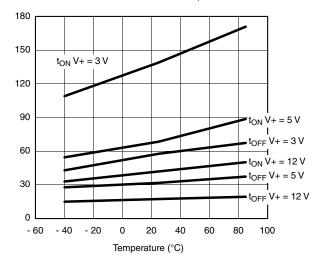
Supply Current vs. Temperature



Switching Current vs. Input Switching Frequency

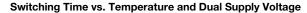
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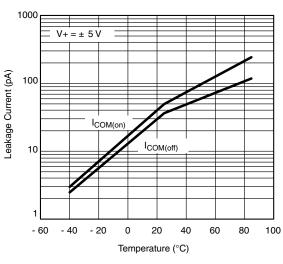
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

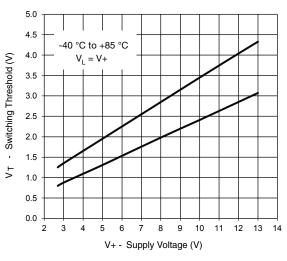


120 $V_{SUPPLY} = \pm 5 V$ 100 80 60 $t_{ON} V_S = -3.5 V$ $t_{ON} V_{S} = 3.5 V$ 40 $t_{OFF} V_S = -3.5 V$ $t_{OFF} V_S = 3.5 V$ 20 - 60 - 40 - 20 0 20 40 60 80 100 Temperature (°C)

Switching Time vs. Temperature and Single Supply Voltage

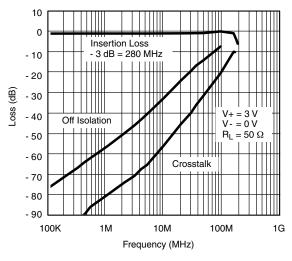






Leakage Current vs. Temperature

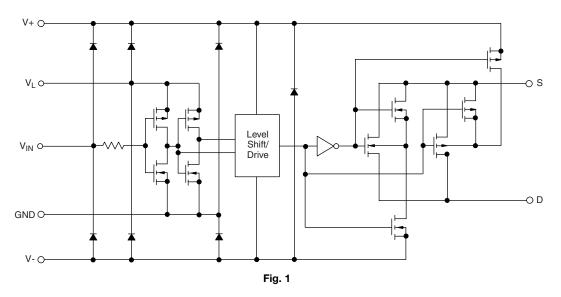
Switching Threshold vs. Supply Voltage



Insertion Loss, Off Isolation and Crosstalk vs. Frequency



SCHEMATIC DIAGRAM (typical channel)



TEST CIRCUITS

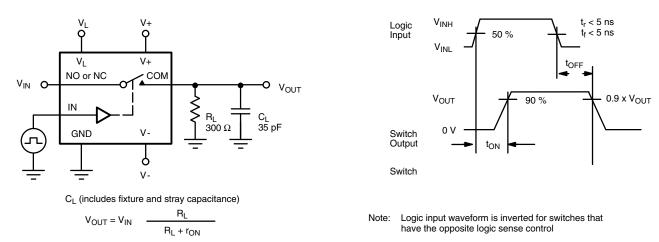


Fig. 2 - Switching Time

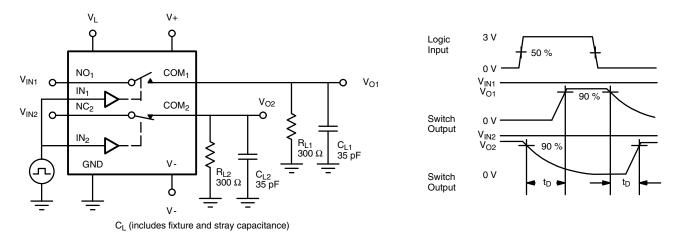


Fig. 3 - Break-Before-Make (DG9426)

 $V_{IN} = 0 - V +$

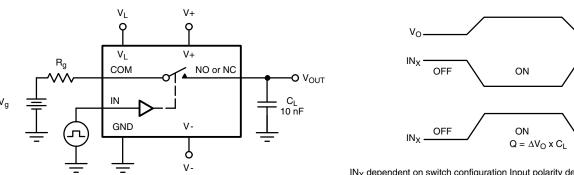
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 ΔV_{O}

OFF

OFF

TEST CIRCUITS



 $\ensuremath{\mathsf{IN}_{\mathsf{X}}}$ dependent on switch configuration Input polarity determined by sense of switch.

Fig. 4 - Charge Injection

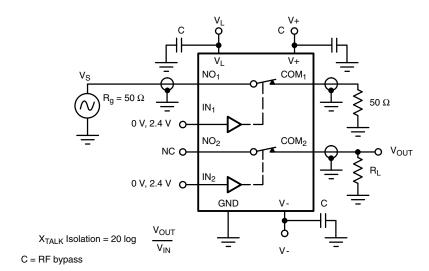


Fig. 5 - Crosstalk

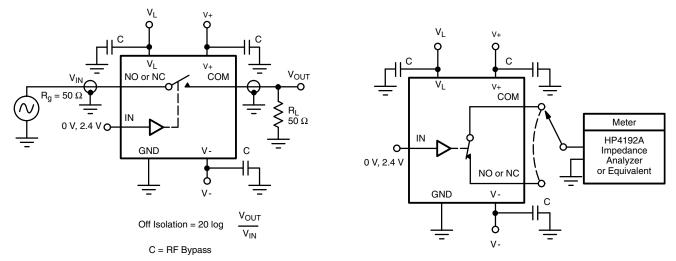


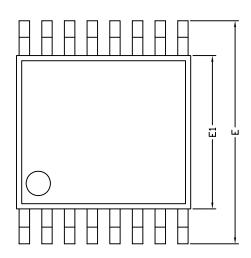
Fig. 6 - Off-Isolation

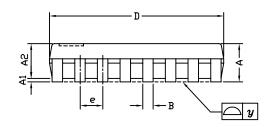
Fig. 7 - Source / Drain Capacitances

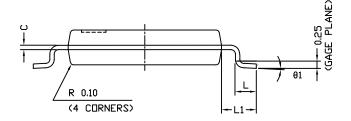
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TSSOP: 16-LEAD







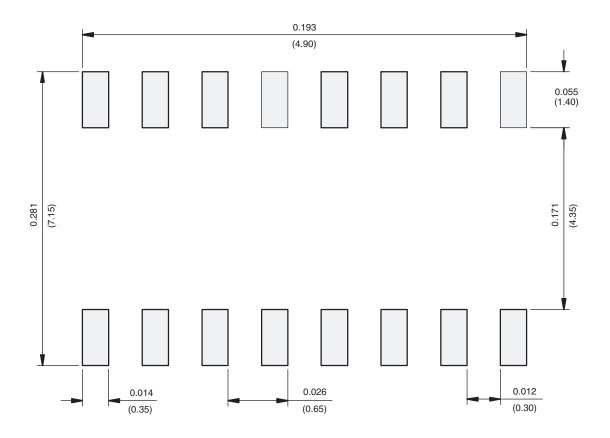
	DII	MENSIONS IN MILLIMETE	RS
Symbols	Min	Nom	Max
А	=	1.10	1.20
A1	0.05	0.10	0.15
A2	=	1.00	1.05
В	0.22	0.28	0.38
С	=	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	=	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D. 23-0	Oct-06	<u> </u>	

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



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